TM3DQ8T

module TM3 - 8 outputs transistor PNP





Main

Range of product	Modicon TM3
Product or component type	Discrete output module
Range compatibility	Modicon M221 Modicon M241 Modicon M251
Discrete output type	Transistor
Discrete output number	8
Discrete output logic	Positive logic (source)
Discrete output voltage	24 V DC for transistor output
Discrete output current	50 mA for transistor output

Complementary

Discrete I/O number	8
Current consumption	5 mA at 5 V DC via bus connector at state off 0 mA at 24 V DC via bus connector at state off 20 mA at 24 V DC via bus connector at state on 10 mA at 5 V DC via bus connector at state on
Response time	450 µs for turn-on 450 µs for turn-off
Leakage current	0.1 mA for transistor output
Voltage drop	0.4 V
Tungsten load	3 W for transistor output
Local signalling	Green for output status
Electrical connection	Removable screw terminal block pitch 5.08 mm with 11 terminal(s) of 2.5 mm ² connection capacity for outputs
Cable length	<= 30 m unshielded cable for transistor output
Insulation	500 V AC between output and internal logic Non-insulated between outputs
Marking	CE
Mounting support	Top hat type TH35-15 rail conforming to IEC 60715 Top hat type TH35-7.5 rail conforming to IEC 60715 Plate or panel with fixing kit
Height	90 mm
Depth	84.6 mm
Width	27.4 mm
Product weight	0.76 kg

Environment

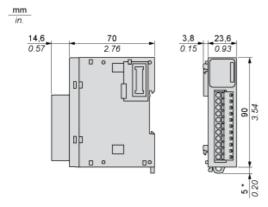
standards	EN/IEC 61131-2 EN/IEC 61010-2-201
product certifications	C-Tick CULus
resistance to electrostatic discharge	4 kV (on contact) conforming to EN/IEC 61000-4-2 8 kV (in air) conforming to EN/IEC 61000-4-2
resistance to electromagnetic fields	10 V/m at 80 MHz1 GHz conforming to EN/IEC 61000-4-3 3 V/m at 1.4 GHz2 GHz conforming to EN/IEC 61000-4-3 1 V/m at 2 GHz3 GHz conforming to EN/IEC 61000-4-3
resistance to magnetic fields	30 A/m at 5060 Hz conforming to EN/IEC 61000-4-8
resistance to fast transients	1 kV for I/O conforming to EN/IEC 61000-4-4
surge withstand	1 kV for I/O (DC) in common mode conforming to EN/IEC 61000-4-5
resistance to conducted disturbances, induced by radio	10 Vrms at 0.1580 MHz conforming to EN/IEC 61000-4-6

frequency fields	3 Vrms at spot frequency (2, 3, 4, 6.2, 8.2, 12.6, 16.5, 18.8, 22, 25 MHz) conforming to
- 1 2	Marine specification (LR, ABS, DNV, GL)
electromagnetic emission	Radiated emissions, test level: 40 dB μ V/m QP with class A, condition of test: 10 m (radio frequency: 30230 MHz) conforming to EN/IEC 55011 Radiated emissions, test level: 47 dB μ V/m QP with class A, condition of test: 10 m (radio frequency: 230 MHz1 GHz) conforming to EN/IEC 55011
ambient air temperature for operation	-1055 °C for horizontal installation -1035 °C for vertical installation
ambient air temperature for storage	-2570 °C
relative humidity	1095 % without condensation in operation 1095 % without condensation in storage
IP degree of protection	IP20 with protective cover in place
pollution degree	2
operating altitude	02000 m
storage altitude	03000 m
vibration resistance	3.5 mm (vibration frequency: 58.4 Hz) on DIN rail 3 gn (vibration frequency: 8.4150 Hz) on DIN rail 3.5 mm (vibration frequency: 58.4 Hz) on panel 3 gn (vibration frequency: 8.4150 Hz) on panel
shock resistance	15 gn (test wave duration:11 ms)

Offer Sustainability

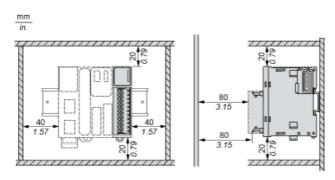
Sustainable offer status	Green Premium product
RoHS (date code: YYWW)	Compliant - since 1348 - Schneider Electric declaration of conformity
REACh	Reference not containing SVHC above the threshold
Product environmental profile	Available
Product end of life instructions	Available

Dimensions



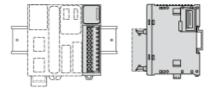
(*) 8.5 mm/0.33 in. when the clamp is pulled out.

Spacing Requirements

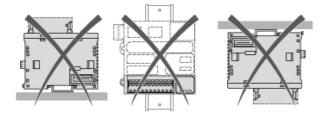


Mounting on a Rail

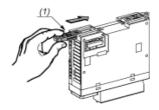




Incorrect Mounting

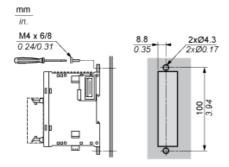


Mounting on a Panel Surface



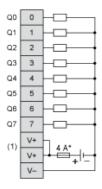
(1) Install a mounting strip

Mounting Hole Layout



Digital Transistor Output Module (8-channel, Source)

Wiring Diagram



- (*) Type T fuse
- (1) The V+ terminals are connected internally.